

采用小型封装且具有 ±15kV IEC ESD 保护功能的 TRSF3221E 3V 至 5.5V 单通道 RS-232 1Mbit/s 线路驱动器和接收器

1 特性

- 为 RS-232 引脚提供 ESD 保护
 - ±15kV 人体放电模型 (HBM)
 - ±8kV IEC 61000-4-2 接触放电
 - ±15kV IEC 61000-4-2 气隙放电
- 由 3V 至 5.5V V_{CC} 电源供电
- 速率高达 1Mbit/s
 - 低速引脚兼容器件 (250kbit/s) - TRS3221E
- 采用近似于芯片级封装的 16 引脚 VQFN (RGT, 比 TSSOP 封装小 82%)
- 低待机电流: 1 μA (典型值)
- 外部电容器: 4 × 0.1 μF
- 接受 5V 逻辑输入及 3.3V 电源
- 自动断电功能可自动禁用驱动器以节省能耗

2 应用

- 工业 PC
- 有线网络
- 数据中心和企业级计算
- 电池供电型系统
- PDA
- 笔记本电脑
- 便携式计算机
- 掌上电脑
- 手持设备

3 说明

TRSF3221E 包含一个线路驱动器、一个线路接收器和一个具有引脚对引脚 (串行端口连接引脚, 包括 GND) ±15kV IEC ESD 保护功能的双电荷泵电路。TRSF3221E 可在异步通信控制器和串行端口连接器之间提供电气接口。电荷泵和四个小型外部电容器支持由 3V 至 5.5V 单电源供电。TRSF3221E 以高达 1Mbit/s 的数据信号传输速率运行, 驱动器输出电压摆率为 24V/μs 至 150V/μs。

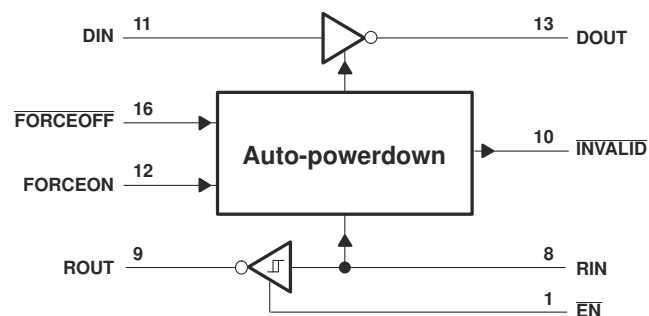
串行端口处于非活动状态时, 可提供灵活的电源管理控制选项。当 FORCEON 为低电平且 FORCEOFF 为高电平时, 自动断电功能启用。在这种运行模式下, 如果 TRSF3221E 在接收器输入端未感应到有效的 RS-232 信号, 则会禁用驱动器输出。如果 FORCEOFF 设定为低电平且使能 (EN) 输入为高电平, 则驱动器和接收器均关闭, 且电源电流降低至 1 μA。断开串行端口的连接或关闭外围驱动器会导致发生自动断电情况。当 FORCEON 和 FORCEOFF 均为高电平时可禁用自动断电。启用自动断电的情况下, 向接收器输入施加有效信号时, 器件会自动激活。INVALID 输出会通知用户接收器输入端是否存在 RS-232 信号。如果接收器输入电压大于 2.7V 或小于 -2.7V, 或者介于 -0.3V 至 0.3V 之间的时间少于 30 μs, 则 INVALID 为高电平 (有效数据)。如果接收器输入电压在 -0.3V 至 0.3V 之间的时间超过 30 μs, 则 INVALID 为低电平 (无效数据)。

有关接收器输入电平的信息, 请参阅图 7-5。

器件信息

| 器件型号 | 封装 ⁽¹⁾ | 封装尺寸 (标称值) |
|-----------|-------------------|-----------------|
| TRSF3221E | DB (SSOP) | 6.20mm x 5.30mm |
| | PW (TSSOP) | 5.00mm x 4.40mm |
| | RGT (VQFN) | 3.00mm x 3.00mm |

(1) 如需了解所有可用封装, 请参阅数据表末尾的可订购产品附录。



逻辑图 (正逻辑)



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4 Revision History

注：以前版本的页码可能与当前版本的页码不同

| Changes from Revision A (May 2021) to Revision B (July 2021) | Page |
|--|-------------|
| • 更改了 <i>应用</i> 列表..... | 1 |
| • Changed the table note for the <i>ESD Ratings - IEC Specifications</i> table to make it also applicable to PW package..... | 4 |
| • Changed the thermal information for PW package..... | 5 |

| Changes from Revision * (August 2007) to Revision A (May 2021) | Page |
|--|-------------|
| • 添加了“器件信息”表、“ESD 等级”表、“特性说明”部分、“器件功能模式”、“应用和实施”部分、“电源相关建议”部分、“布局”部分、“器件和文档支持”部分以及“机械、封装和可订购信息”部分..... | 1 |

5 Pin Configuration and Functions

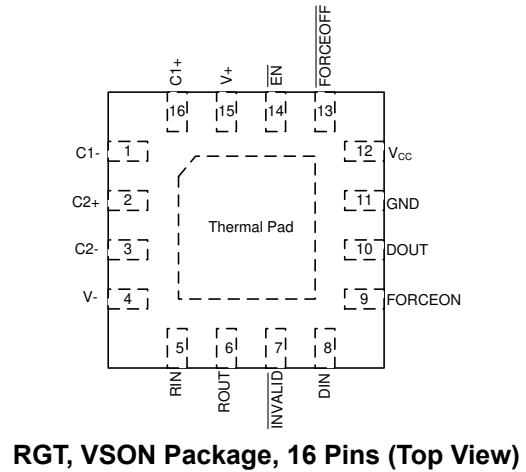
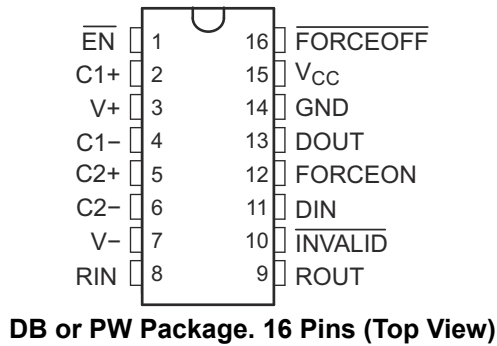


表 5-1. Pin Functions

| NAME | PIN | | I/O ⁽¹⁾ | DESCRIPTION |
|-----------------|----------|-----|--------------------|--|
| | DB or PW | RGT | | |
| EN | 1 | 14 | -- | |
| C1+ | 2 | 16 | - | Positive lead of C1 capacitor |
| V+ | 3 | 15 | O | Positive charge pump output for storage capacitor only |
| C1- | 4 | 1 | - | Negative lead of C1 capacitor |
| C2+ | 5 | 2 | - | Positive lead of C2 capacitor |
| C2- | 6 | 3 | - | Negative lead of C2 capacitor |
| V- | 7 | 4 | O | Negative charge pump output for storage capacitor only |
| RIN | 8 | 5 | I | RS232 line data input (from remote RS232 system) |
| ROUT | 9 | 6 | O | Logic data output (to UART) |
| INVALID | 10 | 7 | | |
| DIN | 11 | 8 | I | Logic data input (from UART) |
| FORCEON | 12 | 9 | | |
| DOUT | 13 | 10 | O | RS232 line data output (to remote RS232 system) |
| GRD | 14 | 11 | - | Ground |
| V _{CC} | 15 | 12 | - | Supply Voltage, Connect to external 3-V to 5.5-V power supply |
| FORCEOFF | 16 | 13 | | |
| Thermal Pad | - | Yes | - | Exposed thermal pad. Can be connected to GND or left floating. |

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) See (1)

| | | MIN | MAX | UNIT | |
|------------------|---|---------------------------------|--------|-----------------------|---|
| V _{CC} | Supply voltage range ⁽²⁾ | - 0.3 | 6 | V | |
| V+ | Positive output supply voltage range ⁽²⁾ | - 0.3 | 7 | V | |
| V- | Negative output supply voltage range ⁽²⁾ | 0.3 | - 7 | V | |
| V+ - V- | Supply voltage difference ⁽²⁾ | | 13 | V | |
| V _I | Input voltage range | Driver (FORCEOFF, FORCEON, EN) | - 0.3 | 6 | V |
| | | Receiver | - 25 | 25 | |
| V _O | Output voltage range | Driver | - 13.2 | 13.2 | V |
| | | Receiver (INVALID) | - 0.3 | V _{CC} + 0.3 | |
| T _J | Operating virtual junction temperature | | 150 | °C | |
| T _{stg} | Storage temperature range | - 65 | 150 | °C | |

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltages are with respect to network GND.

6.2 ESD Ratings

| | | VALUE | UNIT | |
|--------------------|-------------------------|--|-------|---|
| V _(ESD) | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±3000 | V |
| | | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±1500 | |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 ESD Ratings, IEC Specifications

| PIN NAME | TEST CONDITIONS | TYP | UNIT |
|-----------|--|-----|------|
| RIN, DOUT | HBM | ±15 | kV |
| | IEC 61000-4-2 Contact Discharge ⁽¹⁾ | ±8 | |
| | IEC 61000-4-2 Air-Gap Discharge ⁽¹⁾ | ±15 | |

- (1) For the RGT and PW package only, a minimum of 1-μF capacitor is required between VCC and GND to meet the specified IEC-ESD level.

6.4 Recommended Operating Conditions

See 图 9-1 and (1)

| | | | MIN | NOM | MAX | UNIT |
|-----------------|---|----------------------------|-------------------------|-----|-----|------|
| Supply voltage | | V _{CC} = 3.3 V | 3 | 3.3 | 3.6 | V |
| | | V _{CC} = 5 V | 4.5 | 5 | 5.5 | |
| V _{IH} | Driver and control high-level input voltage | DIN, FORCEOFF, FORCEON, EN | V _{CC} = 3.3 V | | 2 | V |
| | | V _{CC} = 5 V | | 2.4 | | |
| V _{IL} | Driver and control low-level input voltage | DIN, FORCEOFF, FORCEON, EN | | | 0.8 | V |
| V _I | Driver and control input voltage | DIN, FORCEOFF, FORCEON | 0 | 5.5 | | V |
| V _I | Receiver input voltage | | -25 | 25 | | V |
| T _A | Operating free-air temperature | TRSF3221EI | -40 | 85 | | °C |
| | | TRSF3221EC | 0 | 70 | | |

(1) Test conditions are C1 - C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2 - C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

6.5 Thermal Resistance Characteristics

| THERMAL METRIC ⁽¹⁾ | | TRSF3221E | | | UNIT |
|-------------------------------|--|-----------|------------|------------|------|
| | | DB (SSOP) | PW (TSSOP) | RGT (VQFN) | |
| | | 16 Pins | 16 Pins | 16 Pins | |
| R _{θJA} | Junction-to-ambient thermal resistance | 82 | 110.9 | 58.8 | °C/W |
| R _{θJC(top)} | Junction-to-case (top) thermal resistance | 45.7 | 41.7 | 55.8 | °C/W |
| R _{θJB} | Junction-to-board thermal resistance | 44.4 | 57.2 | 23.8 | °C/W |
| ψ _{JT} | Junction-to-top characterization parameter | 11.0 | 4.2 | 1.7 | °C/W |
| ψ _{JB} | Junction-to-board characterization parameter | 43.8 | 56.6 | 23.7 | °C/W |
| R _{θJC(bot)} | Junction-to-case (bottom) thermal resistance | N/A | N/A | 9 | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC package thermal metrics](#) application report.

6.6 Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

(see 图 9-1)

| PARAMETER | | TEST CONDITIONS ⁽¹⁾ | MIN | TYP ⁽²⁾ | MAX | UNIT |
|-----------------|--|--------------------------------|---|--------------------|-----|------|
| I _I | Input leakage current | FORCEOFF, FORCEON, EN | | ±0.01 | ±1 | μA |
| I _{CC} | Supply current (T _A = 25°C) | Auto-powerdown disabled | No load, FORCEOFF and FORCEON at V _{CC} | 0.3 | 1 | mA |
| | | Powered off | No load, FORCEOFF at GND | 1 | 10 | |
| | | Auto-powerdown enabled | No load, FORCEOFF at V _{CC} , FORCEON at GND, All RIN are open or grounded | 1 | 10 | μA |

(1) Test conditions are C1 - C4 = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2 - C4 = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

6.7 Electrical Characteristics, Driver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

(see [Figure 9-1](#))

| PARAMETER | TEST CONDITIONS ⁽¹⁾ | MIN | TYP ⁽²⁾ | MAX | UNIT | |
|------------------|---|--|--------------------|-------|------|-----|
| V _{OH} | High-level output voltage | DOUT at R _L = 3 kΩ to GND, DIN = GND | | 5 | 5.4 | V |
| V _{OL} | Low-level output voltage | DOUT at R _L = 3 kΩ to GND, DIN = V _{CC} | | -5 | -5.4 | V |
| I _{IH} | High-level input current | V _I = V _{CC} | | ±0.01 | ±1 | μA |
| I _{IL} | Low-level input current | V _I at GND | | ±0.01 | ±1 | μA |
| I _{OS} | Short-circuit output current ⁽³⁾ | V _{CC} = 3.6 V, V _O = 0 V | | ±35 | ±60 | mA |
| | | V _{CC} = 5.5 V, V _O = 0 V | | ±35 | ±90 | |
| r _o | Output resistance | V _{CC} , V ₊ , and V ₋ = 0 V, V _O = ±2 V | | 300 | 10M | Ω |
| I _{off} | Output leakage current | FORCEOFF = GND, V _O = ±12 V, V _{CC} = 3 V to 3.6 V | | | | ±25 |
| | | V _O = ±10 V, V _{CC} = 4.5 V to 5.5 V | | | | ±25 |

(1) Test conditions are C₁ - C₄ = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C₁ = 0.047 μF, C₂ - C₄ = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

(3) Short-circuit durations must be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output can be shorted at a time.

6.8 Switching Characteristics, Driver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

(see [Figure 9-1](#))

| PARAMETER | TEST CONDITIONS ⁽¹⁾ | MIN | TYP ⁽²⁾ | MAX | UNIT |
|--|---|--|--------------------|-----|--------|
| Maximum data rate (see Figure 7-1) | R _L = 3 kΩ | C _L = 1000 pF | | 250 | kbit/s |
| | | C _L = 250 pF, V _{CC} = 3 V to 4.5 V | 1000 | | |
| | | C _L = 1000 pF, V _{CC} = 4.5 V to 5.5 V | 1000 | | |
| t _{sk(p)} | Pulse skew ⁽³⁾ | C _L = 250 pF, R _L = 3 kΩ Figure 7-2 , RGT Package | 25 | | ns |
| | | C _L = 150 pF to 2500 pF, R _L = 3 kΩ to 7 kΩ, See Figure 7-2 , DB or PW package | 100 | | |
| SR(tr) | Slew rate, transition region (see Figure 7-1) | V _{CC} = 3.3 V, R _L = 3 kΩ to 7 kΩ, C _L = 150 pF to 1000 pF | 18 | 150 | V/μs |

(1) Test conditions are C₁ - C₄ = 0.1 μF at V_{CC} = 3.3 V ± 0.3 V; C₁ = 0.047 μF, C₂ - C₄ = 0.33 μF at V_{CC} = 5 V ± 0.5 V.

(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

(3) Pulse skew is defined as |t_{PLH} - t_{PHL}| of each channel of the same device.

6.9 Electrical Characteristics, Receiver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)
(see [图 9-1](#))

| PARAMETER | | TEST CONDITIONS ⁽¹⁾ | MIN | TYP ⁽²⁾ | MAX | UNIT |
|------------------|---|--------------------------------|-------------------------|-------------------------|-----|------|
| V _{OH} | High-level output voltage | I _{OH} = - 1 mA | V _{CC} - 0.6 V | V _{CC} - 0.1 V | | V |
| V _{OL} | Low-level output voltage | I _{OL} = 1.6 mA | | | 0.4 | V |
| V _{IT+} | Positive-going input threshold voltage | V _{CC} = 3.3 V | | 1.6 | 2.4 | V |
| | | V _{CC} = 5 V | | 1.9 | 2.4 | |
| V _{IT-} | Negative-going input threshold voltage | V _{CC} = 3.3 V | 0.6 | 1.1 | | V |
| | | V _{CC} = 5 V | 0.8 | 1.4 | | |
| V _{hys} | Input hysteresis (V _{IT+} - V _{IT-}) | | | 0.5 | | V |
| I _{off} | Output leakage current | FORCEOFF = 0 V | | ±0.05 | ±10 | μ A |
| r _i | Input resistance | V _I = ±3 V to ±25 V | 3 | 5 | 7 | kΩ |

- (1) Test conditions are C1 - C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2 - C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.
(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

6.10 Switching Characteristics, Receiver

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)
(see [图 9-1](#))

| PARAMETER | | TEST CONDITIONS ⁽¹⁾ | | TYP ⁽²⁾ | UNIT |
|--------------------|---|---|------------------|--------------------|------|
| t _{PLH} | Propagation delay time, low- to high-level output | C _L = 150 pF, See 图 7-3 | RGT package | 100 | ns |
| | | | DB or PW package | 150 | |
| t _{PHL} | Propagation delay time, high- to low-level output | C _L = 150 pF, See 图 7-3 | RGT package | 125 | ns |
| | | | DB or PW package | 150 | |
| t _{en} | Output enable time | C _L = 150 pF, R _L = 3 kΩ, See 图 7-4 | | 200 | ns |
| t _{dis} | Output disable time | C _L = 150 pF, R _L = 3 kΩ, See 图 7-4 | | 200 | ns |
| t _{sk(p)} | Pulse skew ⁽³⁾ | See 图 7-3 | RGT package | 25 | ns |
| | | | DB or PW package | 50 | |

- (1) Test conditions are C1 - C4 = 0.1 μ F at V_{CC} = 3.3 V ± 0.3 V; C1 = 0.047 μ F, C2 - C4 = 0.33 μ F at V_{CC} = 5 V ± 0.5 V.
(2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.
(3) Pulse skew is defined as |t_{PLH} - t_{PHL}| of each channel of the same device.

6.11 Electrical Characteristics, Auto-Powerdown

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)
(see 图 7-5)

| PARAMETER | | TEST CONDITIONS | | MIN | MAX | UNIT |
|------------------|---|-----------------------------------|---------------------|----------------|-----|------|
| $V_{T+(valid)}$ | Receiver input threshold for $\overline{INVALID}$ high-level output voltage | FORCEON = GND, | FORCEOFF = V_{CC} | | 2.7 | V |
| $V_{T-(valid)}$ | Receiver input threshold for $\overline{INVALID}$ high-level output voltage | FORCEON = GND, | FORCEOFF = V_{CC} | - 2.7 | | V |
| $V_{T(invalid)}$ | Receiver input threshold for $\overline{INVALID}$ low-level output voltage | FORCEON = GND, | FORCEOFF = V_{CC} | - 0.3 | 0.3 | V |
| V_{OH} | $\overline{INVALID}$ high-level output voltage | $I_{OH} = - 1$ mA, FORCEON = GND, | FORCEOFF = V_{CC} | $V_{CC} - 0.6$ | | V |
| V_{OL} | $\overline{INVALID}$ low-level output voltage | $I_{OL} = 1.6$ mA, FORCEON = GND, | FORCEOFF = V_{CC} | | 0.4 | V |

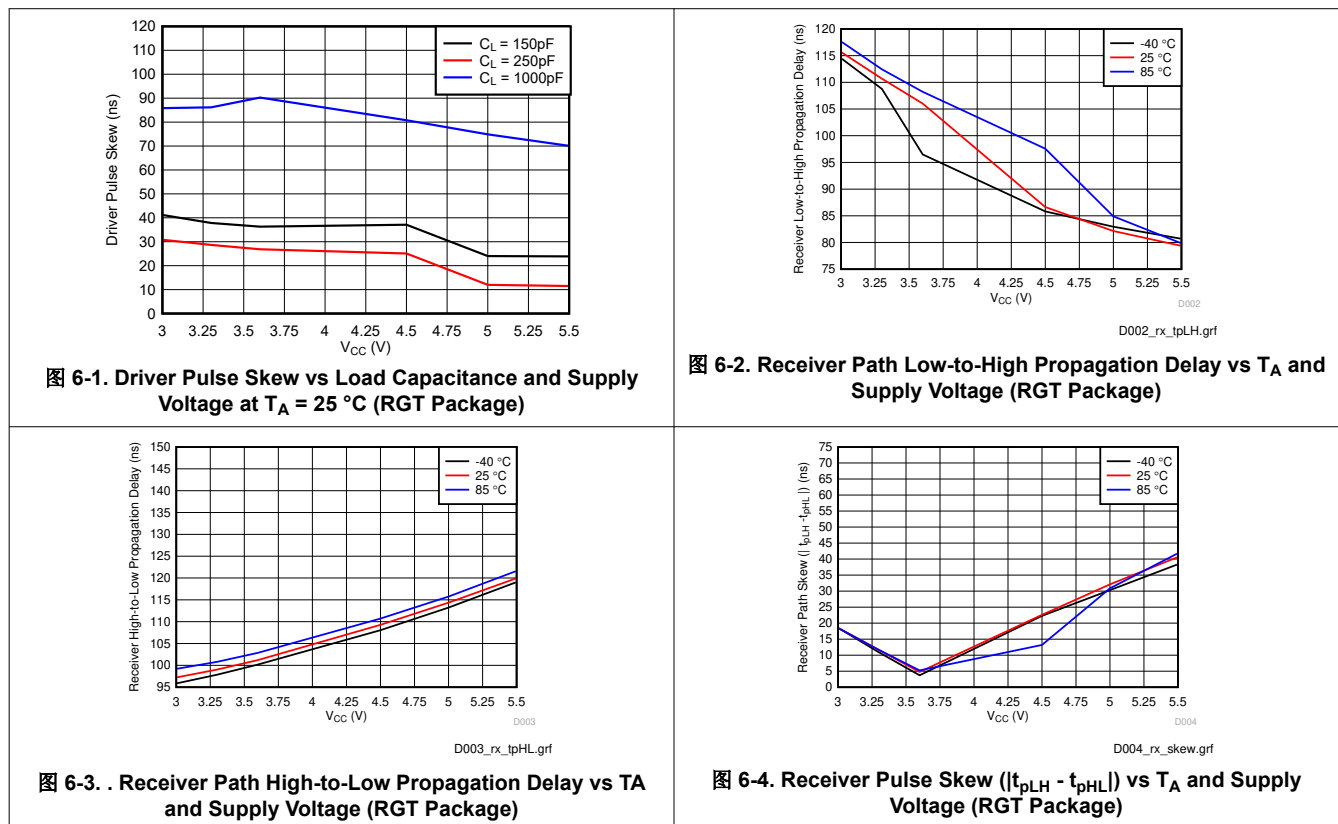
6.12 Switching Characteristics, Auto-Powerdown

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)
(see 图 7-5)

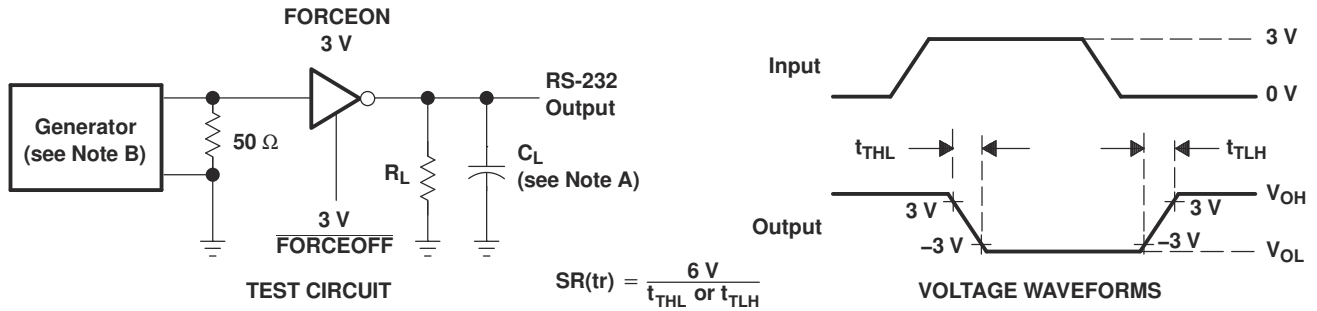
| PARAMETER | | TYP ⁽¹⁾ | UNIT |
|---------------|---|--------------------|---------|
| t_{valid} | Propagation delay time, low- to high-level output | 1 | μ s |
| $t_{invalid}$ | Propagation delay time, high- to low-level output | 30 | μ s |
| t_{en} | Supply enable time | 100 | μ s |

(1) All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25^\circ$ C.

6.13 Typical Characteristics

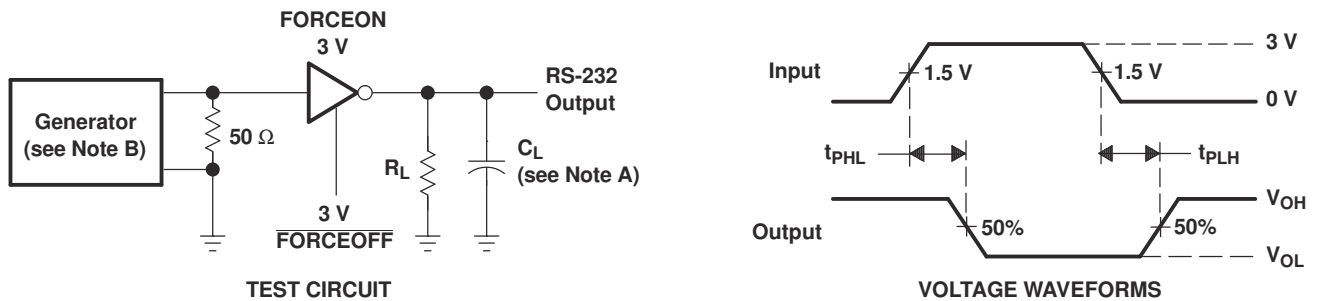


7 Parameter Measurement Information



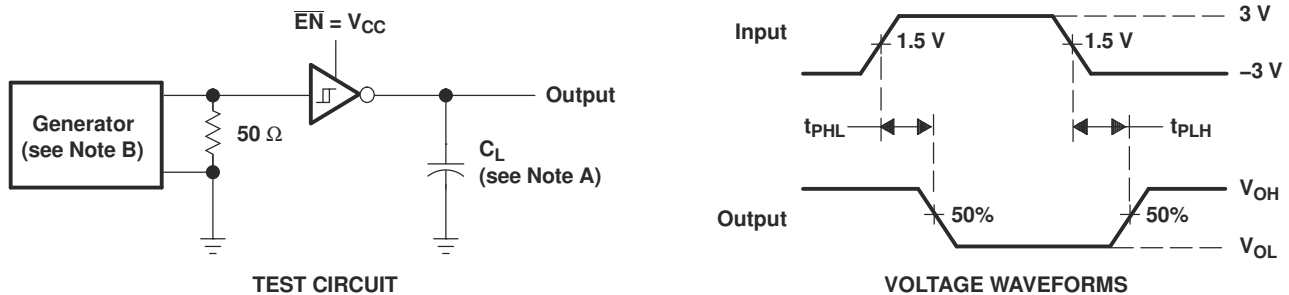
- NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50\ \Omega$, 50% duty cycle, $t_r \leq 10\text{ ns}$, $t_f \leq 10\text{ ns}$.

图 7-1. Driver Slew Rate



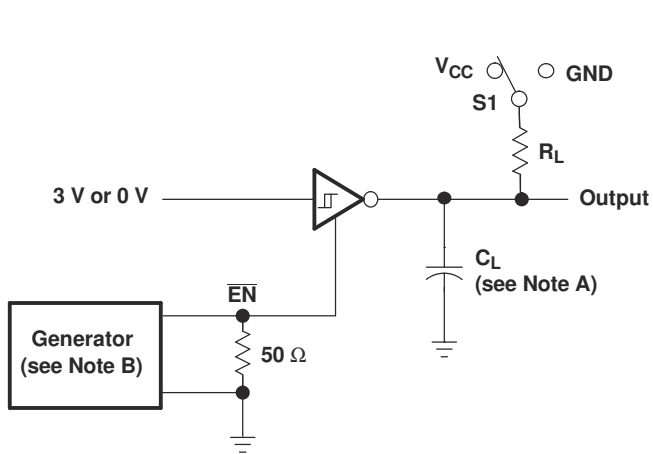
- NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: PRR = 250 kbit/s, $Z_O = 50\ \Omega$, 50% duty cycle, $t_r \leq 10\text{ ns}$, $t_f \leq 10\text{ ns}$.

图 7-2. Driver Pulse Skew

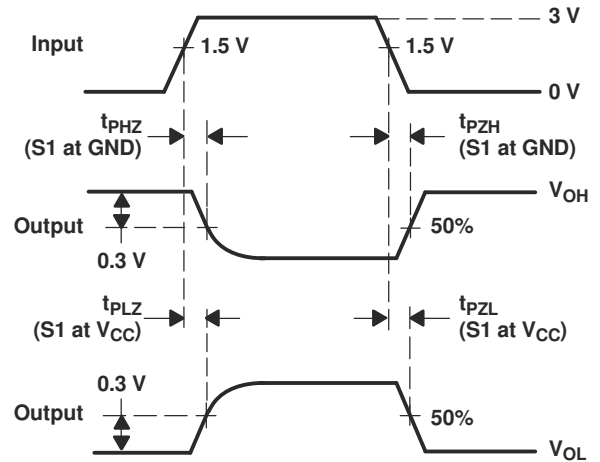


- NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: $Z_O = 50\ \Omega$, 50% duty cycle, $t_r \leq 10\text{ ns}$, $t_f \leq 10\text{ ns}$.

图 7-3. Receiver Propagation Delay Times



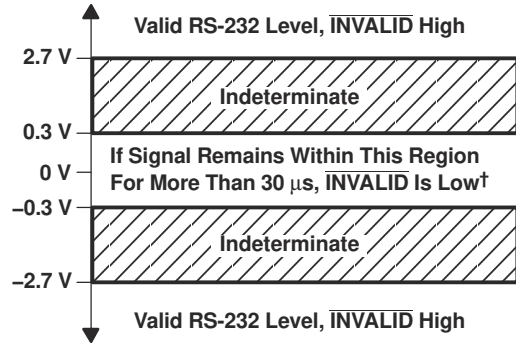
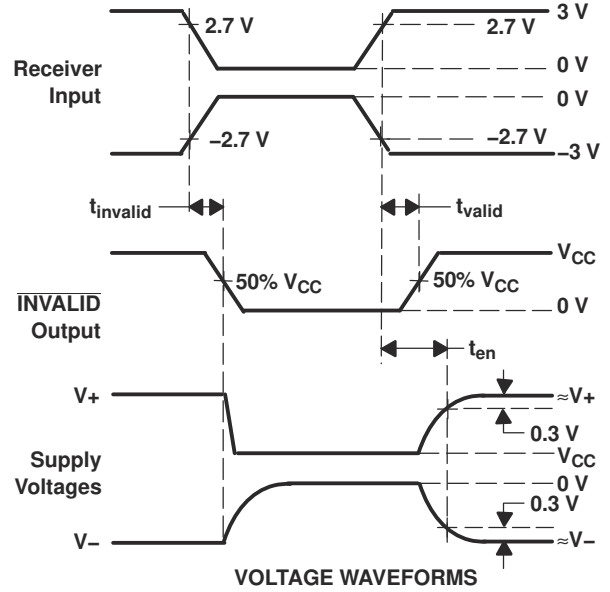
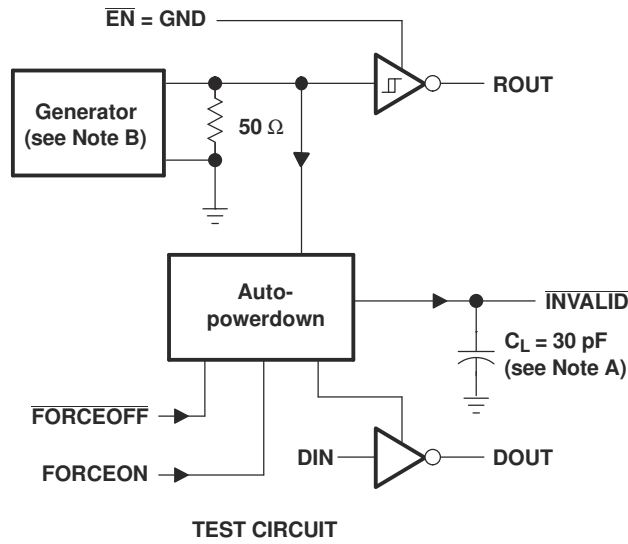
TEST CIRCUIT



VOLTAGE WAVEFORMS

- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: $Z_O = 50\ \Omega$, 50% duty cycle, $t_r \leq 10\ \text{ns}$, $t_f \leq 10\ \text{ns}$.
 - C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - D. t_{PZL} and t_{PZH} are the same as t_{en} .

图 7-4. Receiver Enable and Disable Times



† Auto-powerdown disables drivers and reduces supply current to 1 μA .

- NOTES: A. C_L includes probe and jig capacitance.
B. The pulse generator has the following characteristics: PRR = 5 kbit/s, $Z_O = 50 \Omega$, 50% duty cycle, $t_r \leq 10 \text{ ns}$, $t_f \leq 10 \text{ ns}$.

图 7-5. $\overline{\text{INVALID}}$ Propagation Delay Times and Driver Enabling Time

8 Detailed Description

8.1 Overview

The TRSF3221E consists of one line driver, one line receiver, and a dual charge-pump circuit with ± 15 -kV IEC ESD protection pin to pin (serial-port connection pins, including GND). The TRSF3221E provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The TRSF3221E operates at data signaling rates up to 1 Mbit/s and a driver output slew rate of 24 V/ μ s to 150 V/ μ s.

Flexible control options for power management are available when the serial port is inactive. The auto-powerdown feature functions when FORCEON is low and FORCEOFF is high. During this mode of operation, if the TRSF3221E does not sense a valid RS-232 signal on the receiver input, the driver output is disabled. If FORCEOFF is set low and the enable (EN) input is high, both the driver and receiver are shut off, and the supply current is reduced to 1 μ A. Disconnecting the serial port or turning off the peripheral drivers causes the auto-powerdown condition to occur. Auto-powerdown can be disabled when FORCEON and FORCEOFF are high. With auto-powerdown enabled, the device is activated automatically when a valid signal is applied to the receiver input. The INVALID output notifies the user if an RS-232 signal is present at the receiver input. INVALID is high (valid data) if the receiver input voltage is greater than 2.7 V or less than -2.7 V, or has been between -0.3 V and 0.3 V for less than 30 μ s. INVALID is low (invalid data) if the receiver input voltage is between -0.3 V and 0.3 V for more than 30 μ s.

Outputs are protected against shorts to ground.

8.2 Functional Block Diagram

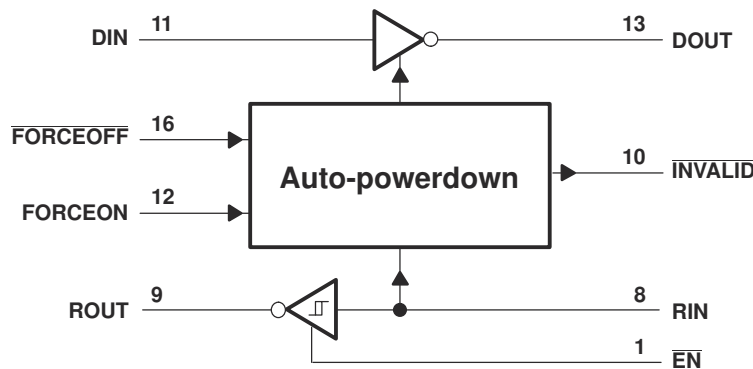


图 8-1. Logic Diagram (Positive Logic)

8.3 Feature Description

The power block increases, inverts, and regulates voltage at V+ and V- pins using a charge pump that requires four external capacitors. Auto-power-down feature for driver is controlled by FORCEON and FORCEOFF inputs. Receiver is controlled by EN input. When MAX3221E is unpowered, it can be safely connected to an active remote RS-232 device.

The driver interfaces the standard logic level to RS232 voltage levels. The DIN input must be valid high or low.

The receiver interfaces RS-232 levels to standard logic levels. An open input results in a high output on ROUT. RIN input includes an internal standard RS-232 load. A logic high input on the EN pin shuts down the receiver output.

8.4 Device Functional Modes

Functional Tables, Each Driver

| INPUTS ⁽¹⁾ | | | | OUTPUT DOUT | DRIVER STATUS |
|-----------------------|---------|----------|---------------------------|----------------|--|
| DIN | FORCEON | FORCEOFF | VALID RIN RS-232 LEVEL | | |
| X | X | L | X | Z | Powered off |
| L | H | H | X | H | Normal operation with auto-powerdown disabled |
| H | H | H | X | L | |
| L | L | H | Yes | H | Normal operation with auto-powerdown enabled |
| H | L | H | Yes | L | |
| L | L | H | No | Z | Powered off by auto-powerdown feature |
| H | L | H | No | Z | |

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

Each Receiver

| INPUTS ⁽¹⁾ | | | OUTPUT ROUT |
|-----------------------|----|---------------------------|----------------|
| RIN | EN | VALID RIN RS-232 LEVEL | |
| L | L | X | H |
| H | L | X | L |
| X | H | X | Z |
| Open | L | No | H |

(1) H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = disconnected input or connected driver off

9 Application and Implementation

Note

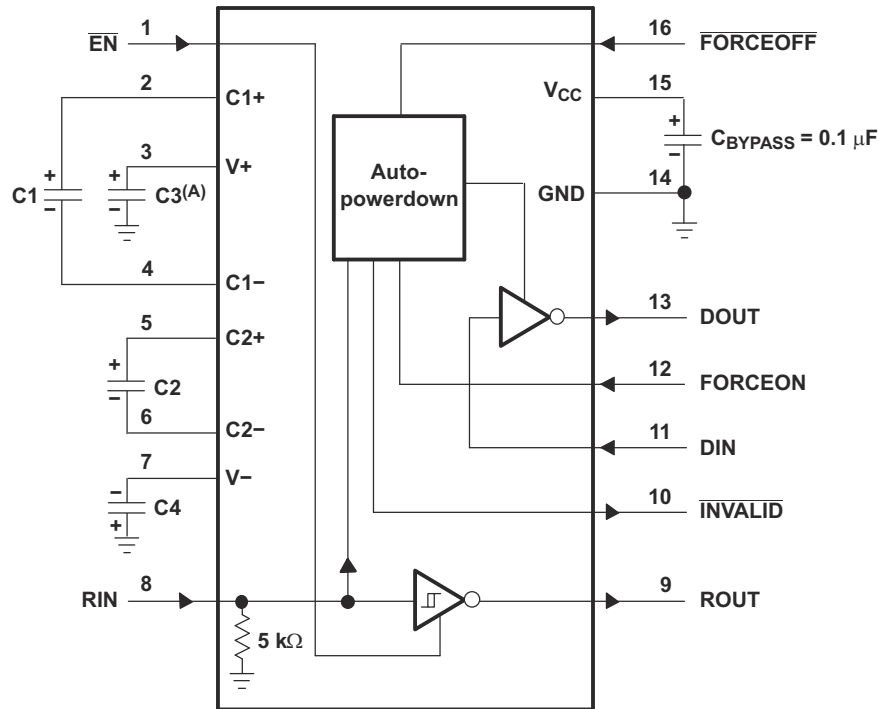
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9.1 Application Information

The TRSF3221E line driver and receiver is a specialized device for 3-V to 5.5-V RS-232 communication applications. This application is a generic implementation of this device with all required external components. For proper operation, add capacitors as shown in 表 9-1.

9.1.1 Typical Application

ROUT and DIN connect to UART or general purpose logic lines. FORCEON and FORCEOFF may be connected to general purpose logic lines or tied to ground or VCC. INVALID may be connected to a general purpose logic line or left unconnected. RIN and DOUT lines connect to a RS-232 connector or cable. DIN, FORCEON, and FORCEOFF inputs must not be left unconnected.



- A. C3 can be connected to V_{CC} or GND.
- B. Resistor values shown are nominal.
- C. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they must be connected as shown.

图 9-1. Typical Operating Circuit and Capacitor Values

表 9-1. V_{CC} vs Capacitor Values

| V _{CC} | C1 | C2, C3, C4 |
|-----------------|----------|------------|
| 3.3 V ± 0.3 V | 0.1 μF | 0.1 μF |
| 5 V ± 0.5 V | 0.047 μF | 0.33 μF |
| 3 V to 5.5 V | 0.1 μF | 0.47 μF |

9.1.1.1 Design Requirements

- Recommended VCC is 3.3 V or 5 V - 3 V to 5.5 V is also possible
- Maximum recommended bit rate is 1 Mbps
- Use capacitors as shown in 图 9-1 and 表 9-1

9.1.1.2 Detailed Design Procedure

For proper operation:

- DIN, FORCEOFF and FORCEON inputs must be connected to valid low or high logic levels
- Select capacitor values based on VCC level for best performance

ROUT and DIN connect to UART or general purpose logic lines. FORCEON and FORCEOFF may be connected general purpose logic lines or tied to ground or VCC. INVALID may be connected to a general purpose logic line or left unconnected. RIN and DOUT lines connect to a RS232 connector or cable. DIN, FORCEON, and FORCEOFF inputs must not be left unconnected.

9.1.2 Application Performance Plot

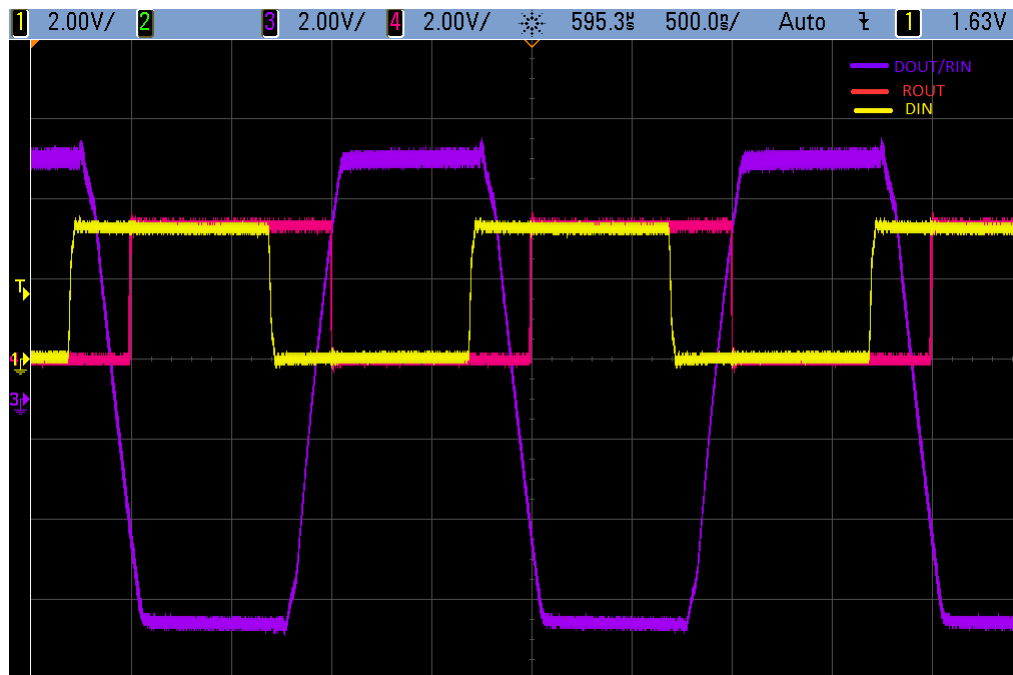


图 9-2. 1 Mbps Driver to Receiver Loopback Timing Waveform, V_{CC} = 3.3 V

10 Power Supply Recommendations

V_{CC} must be between 3 V and 5.5 V. Charge pump capacitors must be chosen using [V_{CC} vs Capacitor Values](#).

11 Layout

11.1 Layout Guidelines

Keep the external capacitor traces short. This is more important on C1 and C2 nodes, which have the fastest rise and fall times.

11.2 Layout Example

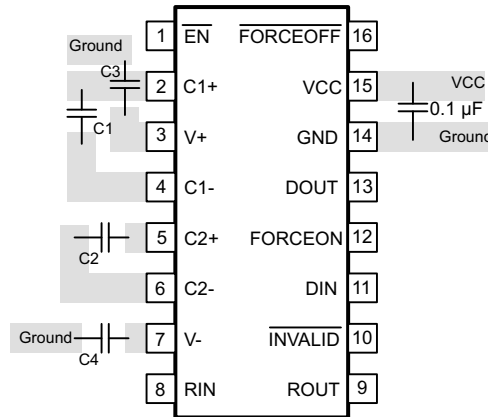


图 11-1. Layout Diagram

12 Device and Documentation Support

12.1 接收文档更新通知

要接收文档更新通知，请导航至 ti.com 上的器件产品文件夹。点击 [订阅更新](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

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ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.5 术语表

TI 术语表 本术语表列出并解释了术语、首字母缩略词和定义。

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|---------|
| TRSF3221ECDB | OBSOLETE | SSOP | DB | 16 | | TBD | Call TI | Call TI | 0 to 70 | RT21EC | |
| TRSF3221ECDBR | ACTIVE | SSOP | DB | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | RT21EC | Samples |
| TRSF3221ECPWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | RT21EC | Samples |
| TRSF3221EIDBR | ACTIVE | SSOP | DB | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | RT21EI | Samples |
| TRSF3221EIPWR | ACTIVE | TSSOP | PW | 16 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | RT21EI | Samples |
| TRSF3221EIRGTR | ACTIVE | VQFN | RGT | 16 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | F3221 | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TRSF3221ECDDBR | SSOP | DB | 16 | 2000 | 330.0 | 16.4 | 8.35 | 6.6 | 2.4 | 12.0 | 16.0 | Q1 |
| TRSF3221ECPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TRSF3221EIDBR | SSOP | DB | 16 | 2000 | 330.0 | 16.4 | 8.35 | 6.6 | 2.4 | 12.0 | 16.0 | Q1 |
| TRSF3221EIPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TRSF3221EIPWR | TSSOP | PW | 16 | 2000 | 330.0 | 12.4 | 6.9 | 5.6 | 1.6 | 8.0 | 12.0 | Q1 |
| TRSF3221EIRGTR | VQFN | RGT | 16 | 3000 | 330.0 | 12.4 | 3.3 | 3.3 | 1.1 | 8.0 | 12.0 | Q2 |

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

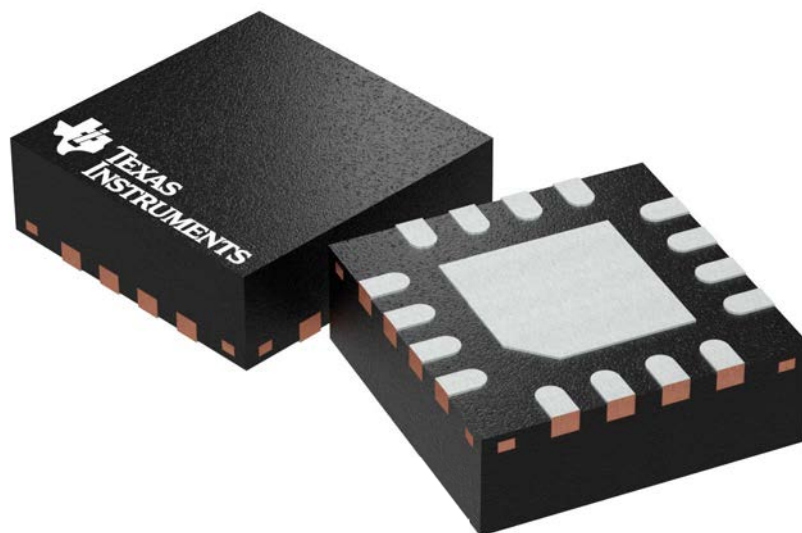
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TRSF3221ECDBR | SSOP | DB | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| TRSF3221ECPWR | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| TRSF3221EIDBR | SSOP | DB | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| TRSF3221EIPWR | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| TRSF3221EIPWR | TSSOP | PW | 16 | 2000 | 356.0 | 356.0 | 35.0 |
| TRSF3221EIRGTR | VQFN | RGT | 16 | 3000 | 367.0 | 367.0 | 35.0 |

RGT 16

GENERIC PACKAGE VIEW

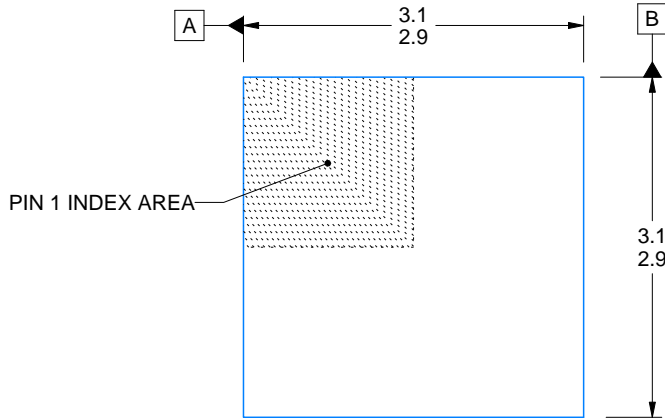
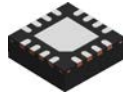
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

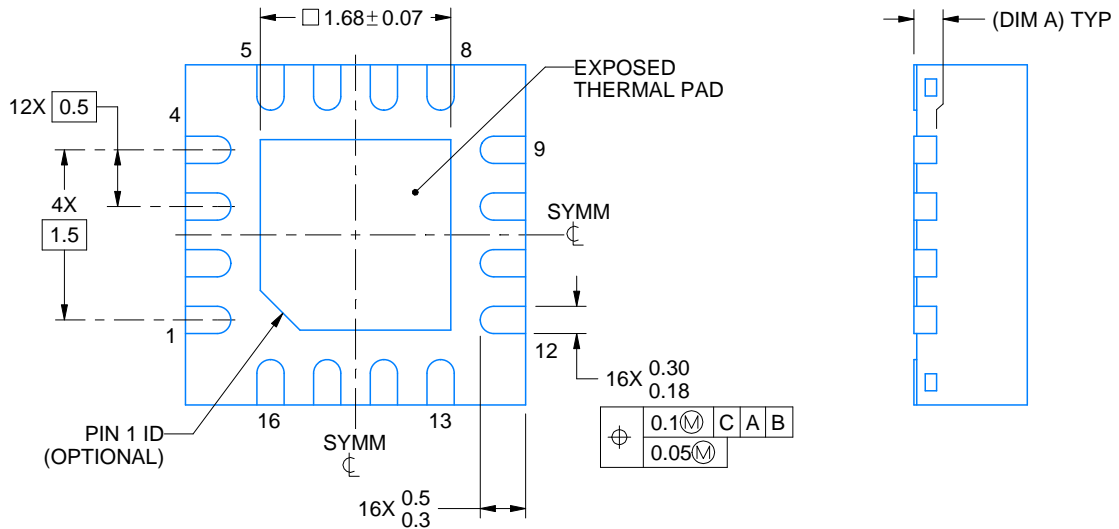
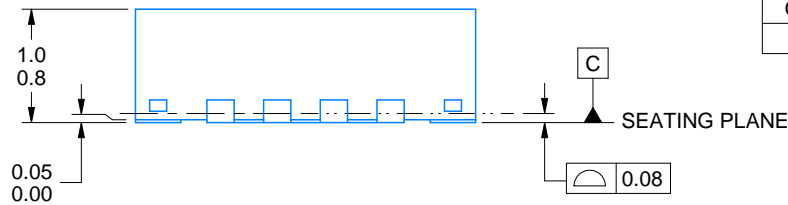


Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4203495/1



| SIDE WALL METAL THICKNESS DIM A | |
|---------------------------------|----------|
| OPTION 1 | OPTION 2 |
| 0.1 | 0.2 |



4222419/D 04/2022

NOTES:

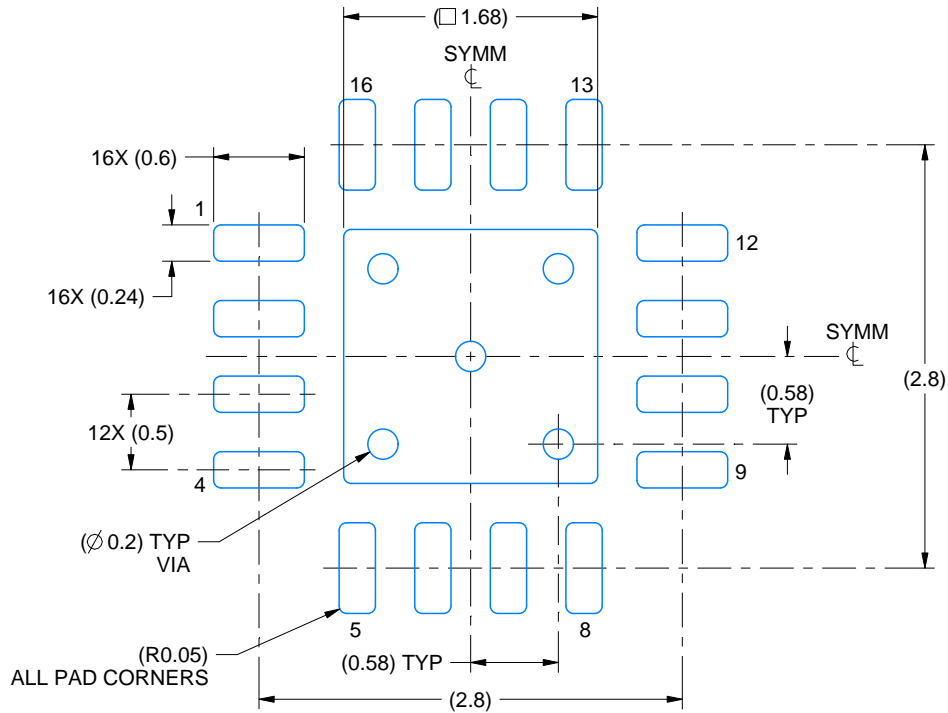
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

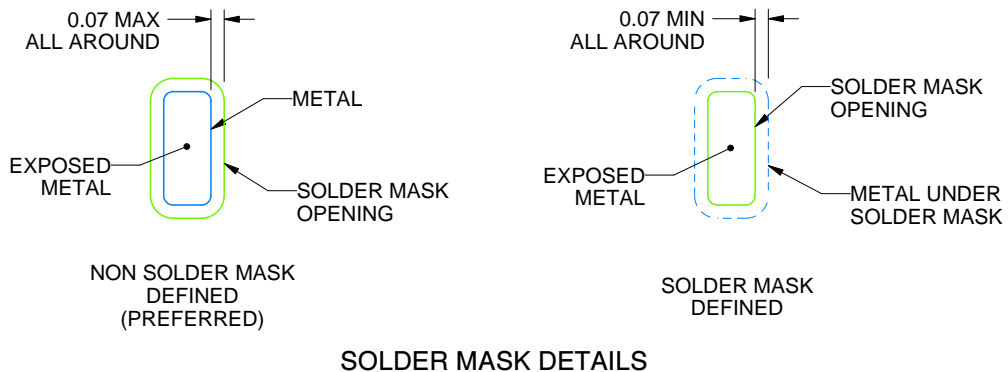
RGT0016C

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X



SOLDER MASK DETAILS

4222419/D 04/2022

NOTES: (continued)

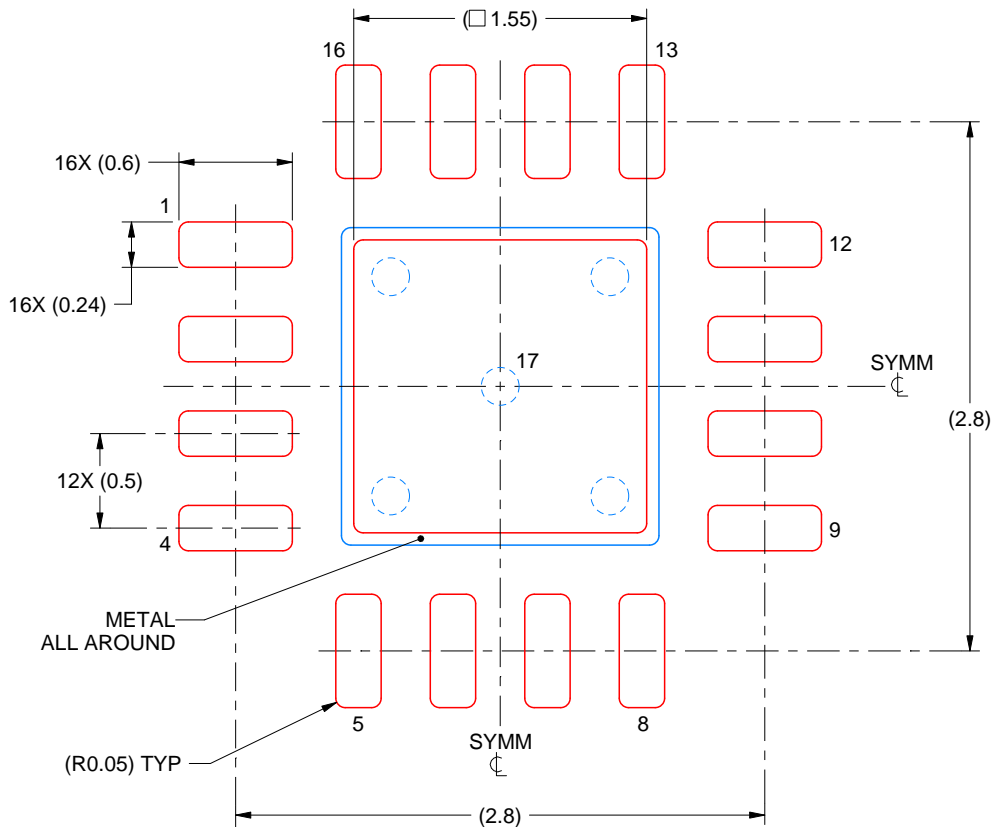
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RGT0016C

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 17:
85% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

4222419/D 04/2022

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



4220204/A 02/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220204/A 02/2017

NOTES: (continued)

- 6. Publication IPC-7351 may have alternate designs.
- 7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/A 02/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DB0016A



PACKAGE OUTLINE

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



4220763/A 05/2022

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-150.

EXAMPLE BOARD LAYOUT

DB0016A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220763/A 05/2022

NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DB0016A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220763/A 05/2022

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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